

3. ELECTRICAL CHARACTERISTICS

3.1 uPD70335-8, 70335-10

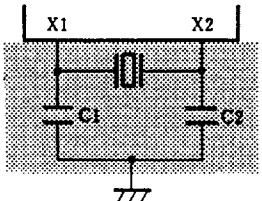
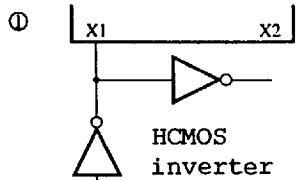
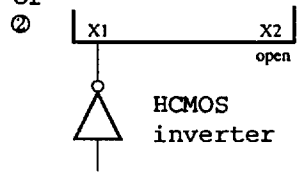
Absolute maximum ratings ($T_a=25^{\circ}\text{C}$)

Parameter	Symbol	Test condition	Ratings	Unit
Power supply voltage	V_{DD}		-0.5 to +7.0	V
	V_{TH}		-0.5 to $V_{DD}+0.5$	V
Input voltage	V_I		-0.5 to $V_{DD}+0.5$	V
Output voltage	V_O		-0.5 to $V_{DD}+0.5$	V
Output low current	I_{OL}	Per pin	4.0	mA
		Total, all output	50	mA
Output high current	I_{OH}	Per pin	-2.0	mA
		Total, all output	-20	mA
Operation temperature	T_{opt}		-10 to +70	$^{\circ}\text{C}$
Storage temperature	T_{stg}		-65 to +150	$^{\circ}\text{C}$

Oscillator characteristics

uPD70335-8 ($T_a = -10$ to $+70^\circ\text{C}$, $V_{DD} = +5.0\text{V} \pm 10\%$, $V_{SS} = 0\text{V}$,
 $0\text{V} \leq V_{TH} \leq V_{DD} + 0.1\text{V}$)

uPD70335-10 ($T_a = -10$ to $+70^\circ\text{C}$, $V_{DD} = +5.0\text{V} \pm 5\%$, $V_{SS} = 0\text{V}$,
 $0\text{V} \leq V_{TH} \leq V_{DD} + 0.1\text{V}$)

Resonator	Recommended circuit	Parameter	uPD70335-8		uPD70335-10		Unit
			MIN.	MAX.	MIN.	MAX.	
Ceramic resonator or crystal resonator		Oscillation frequency (f_{XX})	4	16	4	20	MHz
External clock	①  HCMOS inverter	X1 input frequency (f_X)	4	16	4	20	MHz
	or ②  HCMOS inverter	X1 input rising, falling time (t_{XR} , t_{XF})	0	20	0	15	ns
		X1 input high, low level width (t_{WXH} , t_{WXL})	20		16		ns

Remarks 1: Put the oscillator near to the X1 and X2 pins as much as possible.

2: Do not pass any other signal line through the shaded area.

Recommended oscillator constant

- (1) The following ceramic resonators and external capacitors are recommended:

Manufacturer	Part number	Recommended constant	
		C1[pF]	C2[pF]
MURATA	CSA16.00MX040	30	30
	CSA20.00MX040	10	10
TDK	FCR16.0M2G	30	30

- (2) The following crystal resonators and external capacitors are recommended:

Manufacturer	Part number	Recommended constant	
		C1[pF]	C2[pF]
KINSEKI	HC-49/U (KR-100)	22	22
	HC-49/U (KR-160)	22	22
	HC-49/U (KR-200)	22	22

Remarks: For such as characteristics of each oscillator, confirm to the each maker.

Capacitance ($T_a=25^{\circ}\text{C}$, $V_{DD}=0\text{ V}$)

Parameter	Symbol	Test condition	MIN.	TYP.	MAX.	Unit
Input capacitance	C_I	$f_C=1\text{ MHz}$ Unmeasured pins returned to 0 V			10	pF
Output capacitance	C_O				20	pF
Input/output capacitance	C_{IO}				20	pF

DC characteristics

uPD70335-8 ($T_a = -10$ to $+70^\circ\text{C}$, $V_{DD} = +5.0\text{V} \pm 10\%$)

uPD70335-10 ($T_a = -10$ to $+70^\circ\text{C}$, $V_{DD} = +5.0\text{V} \pm 5\%$)

Parameter	Symbol	Test condition	MIN.	TYP.	MAX.	Unit
Input low voltage	V_{IL}		0		0.8	V
Input high voltage	V_{IH1}	Except for $\overline{\text{RESET}}$, P10/NMI, X1, or X2	2.2		V_{DD}	V
	V_{IH2}	$\overline{\text{RESET}}$, P10/NMI, X1, X2	$0.8V_{DD}$		V_{DD}	V
Output low voltage	V_{OL}	$I_{OL} = 1.6 \text{ mA}$			0.45	V
Output high voltage	V_{OH}	$I_{OH} = -0.4 \text{ mA}$	$V_{DD} - 1.0$			V
Input current	I_I	EA, P10/NMI; $0 \leq V_I \leq V_{DD}$			± 20	μA
Input leakage current	I_{LI}	Except for EA or P10/NMI; $0 \leq V_I \leq V_{DD}$			± 10	μA
Output leakage current	I_{LO}	$0 \leq V_O \leq V_{DD}$			± 10	μA
V_{TH} current	I_{TH}	$0 \text{ V} \leq V_{TH} \leq V_{DD}$		0.5	1.0	mA
V_{DD} power supply current	I_{DD1}	Operation mode	uPD70335-8	65	120	mA
			uPD70335-10	95	130	
	I_{DD2}	HALT mode	uPD70335-8	25	50	mA
			uPD70335-10	30	55	
	I_{DD3}	STOP mode		10	30	μA

AC characteristics

(1) uPD70335-8 ($T_a = -10$ to $+70^\circ\text{C}$, $V_{DD} = +5.0\text{V} \pm 10\%$)

Parameter	Symbol	Test condition	MIN.	MAX.	Unit
X1 input cycle time	t_{CYX}		62	250	ns
X1 input high, low level width	t_{WXH} t_{WXL}		20		ns
X1 input rising, falling time	t_{XR} t_{XF}			20	ns
CLKOUT output cycle time	t_{CYK}	$f_X/2$, $T = t_{CYK}$	125	200	ns
CLKOUT output high, low level width	t_{WKH} t_{WKL}		0.5T-15		ns
CLKOUT output rising, falling time	t_{KR} t_{KF}			15	ns
Input rising, falling time	t_{IR} t_{IF}	Except for $\overline{\text{RESET}}$, NMI, X1 or X2		20	ns
	t_{IRS} t_{IFS}	$\overline{\text{RESET}}$, NMI		30	ns
Output rising, falling time	t_{OR} t_{OF}	Except for CLKOUT		20	ns

Parameter	Symbol	Test condition	MIN.	MAX.	Unit
CLKOUT → address delay time	t_{DKA}		15	90	ns
Address → data input delay time	t_{DADR}			(n+1.5)T-70	ns
$\overline{MREQ} \downarrow \rightarrow$ data delay time	t_{DMRD}			(n+2)T-60	ns
$\overline{MSTB} \downarrow \rightarrow$ data delay time	t_{DMSD}			(n+1)T-60	ns
$\overline{MREQ} \downarrow \rightarrow \overline{MSTB} \downarrow$ delay time	t_{DMRMS1}	Read operation	T-35	T+35	ns
	t_{DMRMS2}	Write operation	(n+1)T-35	(n+1)T+35	ns
$\overline{MREQ}$ low level width	t_{WMRL}		(n+2)T-30	(n+2)T+30	ns
$\overline{MREQ} \downarrow \rightarrow$ Address hold time	t_{HMRA}		0.5T-30		ns
Address hold time from $\overline{MREQ} \uparrow$	t_{HMA}		0.5T-30		ns
Data input hold time from $\overline{MREQ} \uparrow$	t_{HMDR}		0		ns
Control signal recovery time	t_{RVC}		T-25		ns
Address → data output delay time	t_{DADW}		0.5T-35	0.5T+50	ns
Address setup time to $\overline{MREQ} \downarrow$	t_{DAMR}		0.5T-30		ns
Second address setup time to $\overline{MSTB} \downarrow$	t_{DRMS}	Read operation	0.5T-30		ns
	t_{DWMS}	Write operation	(n+0.5)T-30		ns
$\overline{MSTB}$ low level width	t_{WMSL1}	Read operation	(n+1)T-30		ns
	t_{WMSL2}	Write operation	T-30	T+30	ns
Data output setup time to $\overline{MSTB} \uparrow$	t_{SDM}		(n+2)T-50		ns
Address setup time to $\overline{IOSTB} \downarrow$	t_{DAIS}		0.5T-30		ns
$\overline{IOSTB} \downarrow \rightarrow$ data delay time	t_{DISD}			(n+1)T-60	ns
$\overline{MREQ} \downarrow \rightarrow \overline{IOSTB} \downarrow$ delay time	t_{DMRIS}		T-35		ns
$\overline{IOSTB}$ low level width	t_{WISL}		(n+1)T-30		ns
Address hold time from $\overline{IOSTB} \uparrow$	t_{HISA}		0.5T-30		ns
Data input hold time from $\overline{IOSTB} \uparrow$	t_{HISDR}		0		ns
Data output setup time to $\overline{IOSTB} \uparrow$	t_{SDIS}		(n+2)T-50		ns
$\overline{DMARQ}$ setup time to $\overline{MREQ} \downarrow$	t_{SDADQ}	Demand release mode, n≥2		(n-1)T-50	ns
$\overline{DMARQ}$ hold time from $\overline{DMAAK} \downarrow$	t_{HDADQ}	Demand release mode	0		ns
$\overline{DMAAK}$ output low level width	t_{WDMRL}		(n+2.5)T-30		ns
$\overline{DMAAK} \downarrow \rightarrow \overline{TC} \downarrow$ delay time	t_{DDATC}			0.5T+50	ns
$\overline{TC}$ low level width	t_{WTCL}		(n+3)T-30		ns
$\overline{DMAAK}$ output low level width	t_{WDMWL}		(n+2)T-30		ns
Address setup time to $\overline{REFRQ} \downarrow$	t_{DARF}		0.5T-30		ns
$\overline{REFRQ}$ low level width	t_{WRFL}		(n+2)T-30		ns
Address hold time from $\overline{REFRQ} \uparrow$	t_{HRFA}		0.5T-30		ns

Remarks: n denotes the number of wait states. When no wait states are inserted, n is 0.

Parameter	Symbol	Test condition	MIN.	MAX.	Unit
RESET low level width	t_{WRS1}	STOP mode release or power on reset	30		ms
	t_{WRS2}	System reset	5		us
READY setup time to $\overline{MREQ}$ ↓	t_{SCRY0}	$n \geq 2$		2T-100	ns
	t_{SCRY}	$n \geq 3$		nT-100	ns
READY hold time from $\overline{MREQ}$ ↓	t_{HCRY0}	$n = 2$	2T		ns
	t_{HCRY}	$n \geq 3$	nT		ns
	t_{HCRY1}	$n \geq 3$	(n-1)T		ns
READY setup time to $\overline{IOSTB}$ ↓	t_{SSRY0}	$n \geq 2$		T-100	ns
	t_{SSRY}	$n \geq 3$		(n-1)T-100	ns
READY hold time from $\overline{IOSTB}$ ↓	t_{HSRY0}	$n = 2$	T		ns
	t_{HSRY}	$n \geq 3$	(n-1)T		ns
	t_{HSRY1}	$n \geq 3$	(n-2)T		ns
HLDRQ setup time from CLKOUT ↓	t_{SHQK}		30		ns
CLKOUT ↑ → $\overline{HLDAK}$ ↓ delay time	t_{DKHA}		15	80	ns
Bus float → $\overline{HLDAK}$ ↓ delay time	t_{CFHA}		T-50		ns
$\overline{HLDAK}$ ↑ → bus output delay time	t_{DHAC}		T-50		ns
HLDRQ ↓ → $\overline{HLDAK}$ ↑ delay time	t_{DHQHA}			3T+160	ns
HLDRQ ↓ → bus output delay time	t_{DHQC}		3T+30		ns
HLDRQ low level width	t_{WHQL}		1.5T		ns
$\overline{HLDAK}$ low level width	t_{WHAL}		T		ns
INT, DMARQ setup time to CLKOUT ↑	t_{SIQK}		30		ns
INT, DMARQ high, low level width	$t_{WQH'}$ t_{WQL}		8T		ns
POLL setup time to CLKOUT ↑	t_{SPLK}		30		ns
NMI high, low level width	$t_{WNIH'}$ t_{WNIL}		5		us
$\overline{CTS}$ low level width	t_{WCTL}		2T		ns
INT setup time to CLKOUT ↑	t_{SIRK}		30		ns
CLKOUT ↓ → $\overline{INTAK}$ ↓ delay time	t_{DKIA}		15	80	ns
INT hold time from $\overline{INTAK}$ ↓	t_{HIAIQ}		0		ns
$\overline{INTAK}$ low level width	t_{WIAL}		2T-30		ns
$\overline{INTAK}$ high level width	t_{WIAH}		T-30		ns
$\overline{INTAK}$ ↓ → data delay time	t_{DIAD}			2T-130	ns
Data hold time from $\overline{INTAK}$ ↑	t_{HIAD}		0	0.5T	ns

Remarks: n denotes the number of wait states. When no wait states are inserted, n is 0.

Parameter	Symbol	Test condition	MIN.	MAX.	Unit
$\overline{\text{SCKO}}$ cycle time	t_{CYTK}		1000		ns
$\overline{\text{SCKO}}$ high, low level width	t_{WSTH} t_{WSTL}		450		ns
$\overline{\text{SCKO}}$ $\rightarrow$ TxD delay time	t_{DTKD}			210	ns
$\overline{\text{SCKO}}$ $\rightarrow$ TxD hold time	t_{HTKD}		20		ns
$\overline{\text{CTS0}}$ cycle time	t_{CYRK}		1000		ns
$\overline{\text{CTS0}}$ high, low level width	t_{WSRH} t_{WSRL}		420		ns
RxD setup time to, hold time from $\overline{\text{CTS0}}$	t_{SRDK} t_{HKRD}		80		ns

(2) uPD70335-10 ($T_a = -10$ to $+70^\circ\text{C}$, $V_{DD} = +5.0\text{V} \pm 5\%$)

Parameter	Symbol	Test condition	MIN.	MAX.	Unit
X1 input cycle time	t_{CYX}		49	250	ns
X1 input high, low level width	t_{WXH} t_{WXL}		16		ns
X1 input rising, falling time	t_{XR} t_{XF}			15	ns
CLKOUT output cycle time	t_{CYK}	$f_X/2$, $T=t_{CYK}$	100	2000	ns
CLKOUT output high, low level width	t_{WKH} t_{WKL}		0.5T-12		ns
CLKOUT output rising, falling time	t_{KR} t_{KF}			12	ns
Input rising, falling time	t_{IR} t_{IF}	Except for $\overline{\text{RESET}}$, NMI, X1, or X2		20	ns
	t_{IRS} t_{IFS}	$\overline{\text{RESET}}$, NMI		30	ns
Output rising, falling time	t_{OR} t_{OF}	Except for CLKOUT		15	ns
CLKOUT $\rightarrow$ address delay time	t_{DKA}		15	75	ns
Address $\rightarrow$ data input delay time	t_{DADR}			(n+1.5)T-60	ns
$\overline{\text{MREQ}} \downarrow \rightarrow$ data delay time	t_{DMRD}			(n+2)T-50	ns
$\overline{\text{MSTB}} \downarrow \rightarrow$ data delay time	t_{DMSD}			(n+1)T-50	ns
$\overline{\text{MREQ}} \downarrow \rightarrow \overline{\text{MSTB}} \downarrow$ delay time	t_{DMRMS1}	Read operation	T-30	T+30	ns
	t_{DMRMS2}	Write operation	(n+1)T-30	(n+1)T+30	ns
$\overline{\text{MREQ}}$ low level width	t_{WMRL}		(n+2)T-25	(n+2)T+25	ns
Address hold time from $\overline{\text{MREQ}} \downarrow$	t_{HMRA}		0.5T-25		ns
Data input hold time from $\overline{\text{MREQ}} \downarrow$	t_{HMA}		0.5T-30		ns
Data input hold time from $\overline{\text{MREQ}} \downarrow$	t_{HMDR}		0		ns
Control signal recovery time	t_{RVC}		T-25		ns
Address $\rightarrow$ data output delay time	t_{DADW}		0.5T-30	0.5T+50	ns
Address setup time to $\overline{\text{MREQ}} \downarrow$	t_{DAMR}		0.5T-30		ns
Second address setup time to $\overline{\text{MSTB}} \downarrow$	t_{DRMS}	Read operation	0.5T-30		ns
	t_{DWMS}	Write operation	(n+0.5)T-30		ns
$\overline{\text{MSTB}}$ low level width	t_{WMSL1}	Read operation	(n+1)T-25		ns
	t_{WMSL2}	Write operation	T-20	T+20	ns
Data output setup time to $\overline{\text{MSTB}} \downarrow$	t_{SDM}		(n+2)T-50		ns
Address setup time to $\overline{\text{IOSTB}} \downarrow$	t_{DAIS}		0.5T-30		ns
$\overline{\text{IOSTB}} \downarrow \rightarrow$ data delay time	t_{DISD}			(n+1)T-50	ns
$\overline{\text{MREQ}} \downarrow \rightarrow \overline{\text{IOSTB}} \downarrow$ delay time	t_{DMRIS}		T-30		ns
$\overline{\text{IOSTB}}$ low level width	t_{WISL}		(n+1)T-25		ns
Address hold time from $\overline{\text{IOSTB}} \downarrow$	t_{HISA}		0.5T-30		ns
Data input hold time from $\overline{\text{IOSTB}} \downarrow$	t_{HISDR}		0		ns
Data output setup time to $\overline{\text{IOSTB}} \downarrow$	t_{SDIS}		(n+2)T-50		ns

Remarks: n denotes the number of wait states. When no wait states are inserted, n is 0.

Parameter	Symbol	Test condition	MIN.	MAX.	Unit
$\overline{\text{DMARQ}}$ setup time to $\overline{\text{MREQ}} \downarrow$	t_{SDADQ}	Demand release mode, $n \geq 2$		$(n-1)T-50$	ns
$\overline{\text{DMARQ}}$ hold time from $\overline{\text{DMAAK}} \downarrow$	t_{HDADQ}	Demand release mode	0		ns
$\overline{\text{DMAAK}}$ output low level width	t_{WDMRL}		$(n+2.5)T-25$		ns
$\overline{\text{DMAAK}} \downarrow \rightarrow \overline{\text{TC}} \downarrow$ delay time	t_{DDATC}			$0.5t+35$	ns
$\overline{\text{TC}}$ low level width	t_{WTCL}		$(n+3)T-25$		ns
$\overline{\text{DMAAK}}$ output low level width	t_{WDMWL}		$(n+2)T-25$		ns
Address setup time to $\overline{\text{REFRQ}} \downarrow$	t_{DARF}		$0.5T-30$		ns
$\overline{\text{REFRQ}}$ low level width	t_{WRFL}		$(n+2)T-25$		ns
Address hold time from $\overline{\text{REFRQ}} \downarrow$	t_{HRFA}		$0.5T-30$		ns
$\overline{\text{RESET}}$ low level width	t_{WRSL1}	STOP mode release or power on reset	30		ms
	t_{WRSL2}	System reset	5		us
READY setup time to $\overline{\text{MREQ}} \downarrow$	t_{SCRY0}	$n \geq 2$		$2T-80$	ns
	t_{SCRY}	$n \geq 3$		$nT-80$	ns
READY hold time from $\overline{\text{MREQ}} \downarrow$	t_{HCRY0}	$n=2$	$2T$		ns
	t_{HCRY}	$n \geq 3$	nT		ns
	t_{HCRY1}	$n \geq 3$	$(n-1)T$		ns
READY setup time to $\overline{\text{IOSTB}} \downarrow$	t_{SSRY0}	$n \geq 2$		$T-80$	ns
	t_{SSRY}	$n \geq 3$		$(n-1)T-80$	ns
READY hold time from $\overline{\text{IOSTB}} \downarrow$	t_{HSRY0}	$n=2$	T		ns
	t_{HSRY}	$n \geq 3$	$(n-1)T$		ns
	t_{HSRY1}	$n \geq 3$	$(n-2)T$		ns
HLD $\overline{\text{RQ}}$ setup time to CLKOUT $\uparrow$	t_{SHQK}		25		ns
CLKOUT $\uparrow \rightarrow \overline{\text{HLD\overline{AK}}} \downarrow$ delay time	t_{DKHA}		15	70	ns
Bus float $\rightarrow \overline{\text{HLD\overline{AK}}} \downarrow$ delay time	t_{CFHA}		$T-35$		ns
$\overline{\text{HLD\overline{AK}}} \uparrow \rightarrow$ bus output delay time	t_{DHAC}		$T-35$		ns
HLD $\overline{\text{RQ}} \downarrow \rightarrow \overline{\text{HLD\overline{AK}}} \uparrow$ delay time	t_{DHQHA}			$3T+160$	ns
HLD $\overline{\text{RQ}} \downarrow \rightarrow$ bus output delay time	t_{DHQC}		$3T+30$		ns
HLD $\overline{\text{RQ}}$ low level width	t_{WHQL}		$1.5T$		ns
$\overline{\text{HLD\overline{AK}}}$ low level width	t_{WHAL}		T		ns
INTP, DMARQ setup time to CLKOUT $\uparrow$	t_{SIQK}		25		ns
INTP, DMARQ high, low level width	t_{WIQH} t_{WIQL}		$8T$		ns
POLL setup time to CLKOUT $\uparrow$	t_{SPLK}		25		ns
NMI high, low level width	t_{WNIH} t_{WNIL}		5		us
$\overline{\text{CTS}}$ low level width	t_{WCTL}		$2T$		ns

Remarks: n denotes the number of wait states. When no wait states are inserted, n is 0.

Parameter	Symbol	Test condition	MIN.	MAX.	Unit
INT setup time to CLKOUT ↓	t_{SIRK}		25		ns
CLKOUT ↓ → INTAK ↓ delay time	t_{DKIA}		15	70	ns
INT hold time from INTAK ↓	t_{HIAIQ}		0		ns
INTAK low level width	t_{WIAL}		2T-25		ns
INTAK high level width	t_{WIAH}		T-25		ns
INTAK ↓ → data delay time	t_{DIAD}			2T-100	ns
Data hold time from INTAK ↓	t_{HIAD}		0	0.5T	ns
SKO cycle time	t_{CYTK}		1000		ns
SKO high, low level width	t_{WSTH} t_{WSTL}		450		ns
SKO ↓ → TxD delay time	t_{DTKD}			210	ns
SKO ↓ → TxD hold time	t_{HTKD}		20		ns
CTS0 cycle time	t_{CYRK}		1000		ns
CTS0 high, low level width	t_{WSRH} t_{WSRL}		420		ns
RxD setup time to, hold time from CTS0 ↓	t_{SRDK} t_{HKRD}		80		ns

Comparator characteristics

uPD70335-8 ($T_a = -10$ to $+70^\circ\text{C}$, $V_{DD} = +5.0\text{V} \pm 10\%$)

uPD70335-10 ($T_a = -10$ to $+70^\circ\text{C}$, $V_{DD} = +5.0\text{V} \pm 5\%$)

Parameter	Symbol	Test condition	MIN.	TYP.	MAX.	Unit
Comparison accuracy	V_{ACOMP}				± 100	mV
Threshold voltage	V_{TH}		0		$V_{DD} + 0.1$	V
Comparison time	t_{COMP}		64		65	t_{CYK}
PT input voltage	V_{IPT}		0		V_{DD}	V

Data memory STOP mode low supply voltage data retention characteristics ($T_a = -10$ to $+70^\circ\text{C}$)

Parameter	Symbol	Test condition	MIN.	MAX.	Unit
Data retention supply voltage	V_{DDDR}		2.5	5.5	V
V_{DD} rising, falling time	t_{RVD} , t_{FVD}		200		us

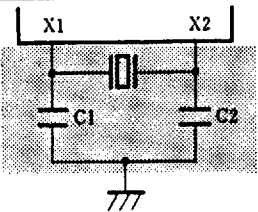
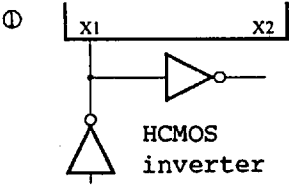
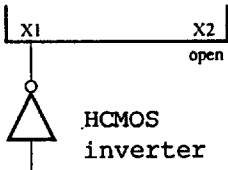
3.2 uPD70335(A)-9

Absolute maximum ratings ($T_a=25^{\circ}\text{C}$)

Parameter	Symbol	Test condition	Ratings	Unit
Power supply voltage	V_{DD}		-0.5 to +7.0	V
	V_{TH}		-0.5 to $V_{DD}+0.5$	V
Input voltage	V_I		-0.5 to $V_{DD}+0.5$	V
Output voltage	V_O		-0.5 to $V_{DD}+0.5$	V
Output low current	I_{OL}	Per pin	4.0	mA
		Total, all output	50	mA
Output high current	I_{OH}	Per pin	-2.0	mA
		Total, all output	-20	mA
Operation temperature	T_{opt}		-40 to +85	$^{\circ}\text{C}$
Storage temperature	T_{stg}		-65 to +150	$^{\circ}\text{C}$

Oscillator characteristics

uPD70335(A)-9 ($T_a = -40$ to $+85^\circ\text{C}$, $V_{DD} = +5.0\text{V} \pm 5\%$, $V_{SS} = 0\text{V}$,
 $0\text{V} \leq V_{TH} \leq V_{DD} + 0.1\text{V}$)

Resonator	Recommended circuit	Parameter	MIN.	MAX.	Unit
Ceramic resonator or crystal resonator		Oscillation frequency (f_{XX})	4	18	MHz
External clock	①  HCMOS inverter or ②  HCMOS inverter	X1 input frequency (f_X)	4	18	MHz
		X1 input rising, falling time (t_{XR} , t_{XF})	0	15	ns
		X1 input high, low level width (t_{WXH} , t_{WXL})	17		ns

Remarks 1: Place the oscillator as close as possible to the X1 and X2 pins.

2: Do not pass any other signal line through the shaded portion.

Capacitance ($T_a=25^\circ\text{C}$, $V_{DD}=0\text{ V}$)

Parameter	Symbol	Test condition	MIN.	TYP.	MAX.	Unit
Input capacitance	C_I	$f_C=1\text{ MHz}$ Unmeasured pins returned to 0 V			10	pF
Output capacitance	C_O				20	pF
Input/output capacitance	C_{IO}				20	pF

DC characteristics

uPD70335(A)-9 ($T_a=-40\text{ to }+85^\circ\text{C}$, $V_{DD}=+5.0\text{V}\pm 5\%$)

Parameter	Symbol	Test condition	MIN.	TYP.	MAX.	Unit
Input low voltage	V_{IL}		0		0.8	V
Input high voltage	V_{IH1}	Except for $\overline{\text{RESET}}$, P10/NMI, X1, or X2	2.2		V_{DD}	V
	V_{IH2}	$\overline{\text{RESET}}$, P10/NMI, X1, X2	$0.8V_{DD}$		V_{DD}	V
Output low voltage	V_{OL}	$I_{OL}=1.6\text{ mA}$			0.45	V
Output high voltage	V_{OH}	$I_{OH}=-0.4\text{ mA}$	$V_{DD}-1.0$			V
Input current	I_I	$\overline{\text{EA}}$, P10/NMI; $0 \leq V_I \leq V_{DD}$			± 20	μA
Input leakage current	I_{LI}	Except for $\overline{\text{EA}}$ or P10/NMI; $0 \leq V_I \leq V_{DD}$			± 10	μA
Output leakage current	I_{LO}	$0 \leq V_O \leq V_{DD}$			± 10	μA
V_{TH} current	I_{TH}	$0\text{ V} \leq V_{TH} \leq V_{DD}$		0.5	1.0	mA
V_{DD} power supply current	I_{DD1}	Operation mode		95	130	mA
	I_{DD2}	HALT mode		30	55	mA
	I_{DD3}	STOP mode		15	35	μA

AC characteristics

uPD70335(A)-9 (Ta=-40 to +85°C, V_{DD}=+5.0V±5%)

Parameter	Symbol	Test condition	MIN.	MAX.	Unit
X1 input cycle time	t _{CYX}		55	250	ns
X1 input high, low level width	t _{WXH} t _{WXL}		17		ns
X1 input rising, falling time	t _{XR} t _{XF}			15	ns
CLKOUT output cycle time	t _{CYK}	f _X /2, T-t _{CYK}	111	2000	ns
CLKOUT output high, low level width	t _{WKH} t _{WKL}		0.5T-12		ns
CLKOUT output rising, falling time	t _{KR} t _{KF}			12	ns
Input rising, falling time	t _{IR} t _{IF}	Except for RESET, NMI, X1 or X2		20	ns
	t _{IRS} t _{IFS}	RESET, NMI		30	ns
Output rising, falling time	t _{OR} t _{OF}	Except for CLKOUT		15	ns
CLKOUT → address delay time	t _{DKA}		15	80	ns
Address → data input delay time	t _{DADR}			(n+1.5)T-60	ns
MREQ ↓ → data delay time	t _{DMRD}			(n+2)T-50	ns
MSTB ↓ → data delay time	t _{DMSD}			(n+1)T-50	ns
MREQ ↓ → MSTB ↓ delay time	t _{DMRMS1}	Read operation	T-30	T+30	ns
	t _{DMRMS2}	Write operation	(n+1)T-30	(n+1)T+30	ns
MREQ low level width	t _{WMRL}		(n+2)T-25	(n+2)T+25	ns
MREQ ↓ → address hold time	t _{HMRA}		0.5T-30		ns
Address hold time from MREQ ↑	t _{HMA}		0.5T-35		ns
Data input hold time from MREQ ↑	t _{HMDR}		0		ns
Control signal recovery time	t _{RVC}		T-25		ns
Address → data output delay time	t _{DADW}			0.5T+50	ns
Address setup time to MREQ ↓	t _{DAMR}		0.5T-35		ns
Second address setup time to MSTB ↓	t _{DRMS}	Read operation	0.5T-30		ns
	t _{DWMS}	Write operation	(n+0.5)T-30		ns
MSTB low level width	t _{WMSL1}	Read operation	(n+1)T-25		ns
	t _{WMSL2}	Write operation	T-25	T+25	ns
Data output setup time to MSTB ↑	t _{SDM}		(n+2)T-50		ns
Address setup time to IOSTB ↓	t _{DAIS}		0.5T-30		ns
IOSTB ↓ → data delay time	t _{DISD}			(n+1)T-50	ns
MREQ ↓ → IOSTB ↓ delay time	t _{DMRIS}		T-35		ns
IOSTB low level width	t _{WISL}		(n+1)T-30		ns
Address hold time from IOSTB ↑	t _{HISA}		0.5T-30		ns
Data input hold time from IOSTB ↑	t _{HISDR}		0		ns
Data output setup time to IOSTB ↑	t _{SDIS}		(n+2)T-50		ns

Remarks: n represents the number of wait states. n=0 means no wait.

Parameter	Symbol	Test condition	MIN.	MAX.	Unit
D $\overline{\text{MARQ}}$ setup time to $\overline{\text{MREQ}}$ ↓	t_{SDADQ}	Demand release mode, $n \geq 2$		$(n-1)T-50$	ns
D $\overline{\text{MARQ}}$ hold time from $\overline{\text{DMAAK}}$ ↓	t_{HDADQ}	Demand release mode	0		ns
D $\overline{\text{MAAK}}$ output low level width	t_{WDMRL}		$(n+2.5)T-25$		ns
D $\overline{\text{MAAK}}$ ↓ → TC ↓ delay time	t_{DDATC}			$0.5T+35$	ns
TC low level width	t_{WTCL}		$(n+3)T-25$		ns
D $\overline{\text{MAAK}}$ output low level width	t_{WDMWL}		$(n+2)T-25$		ns
Address setup time to $\overline{\text{REFRQ}}$ ↓	t_{DARF}		$0.5T-35$		ns
$\overline{\text{REFRQ}}$ low level width	t_{WRFL}		$(n+2)T-25$		ns
Address hold time from $\overline{\text{REFRQ}}$ ↓	t_{HRFA}		$0.5T-35$		ns
$\overline{\text{RESET}}$ low level width	t_{WRSL1}	STOP mode release/ power on reset	30		ms
	t_{WRSL2}	System reset	5		us
READY setup time to $\overline{\text{MREQ}}$ ↓	t_{SCRY0}	$n \geq 2$		$2T-80$	ns
	t_{SCRY}	$n \geq 3$		$nT-80$	ns
READY hold time from $\overline{\text{MREQ}}$ ↓	t_{HCRY0}	$n=2$	$2T$		ns
	t_{HCRY}	$n \geq 3$	nT		ns
	t_{HCRY1}	$n \geq 3$	$(n-1)T$		ns
READY setup time to $\overline{\text{IOSTB}}$ ↓	t_{SSRY0}	$n \geq 2$		$T-80$	ns
	t_{SSRY}	$n \geq 3$		$(n-1)T-80$	ns
READY hold time from $\overline{\text{IOSTB}}$ ↓	t_{HSRY0}	$n=2$	T		ns
	t_{HSRY}	$n \geq 3$	$(n-1)T$		ns
	t_{HSRY1}	$n \geq 3$	$(n-2)T$		ns
H $\overline{\text{LDRQ}}$ setup time to CLKOUT ↑	t_{SHQK}		25		ns
CLKOUT ↑ → H $\overline{\text{LDAK}}$ ↓ delay time	t_{DKHA}		15	75	ns
Bus float → H $\overline{\text{LDAK}}$ ↓ delay time	t_{CPHA}		$T-35$		ns
H $\overline{\text{LDAK}}$ ↓ → bus output delay time	t_{DHAC}		$T-35$		ns
H $\overline{\text{LDRQ}}$ ↓ → H $\overline{\text{LDAK}}$ ↓ delay time	t_{DHQHA}			$3T+160$	ns
H $\overline{\text{LDRQ}}$ ↓ → bus output delay time	t_{DHQC}		$3T+30$		ns
H $\overline{\text{LDRQ}}$ low level width	t_{WHQL}		$1.5T$		ns
H $\overline{\text{LDAK}}$ low level width	t_{WHAL}		T		ns
INT, D $\overline{\text{MARQ}}$ setup time to CLKOUT ↑	t_{SIQK}		25		ns
INT, D $\overline{\text{MARQ}}$ high, low level width	t_{WIQH} t_{WIQL}		$8T$		ns
POLL setup time to CLKOUT ↑	t_{SPLK}		30		ns
NMI high, low level width	t_{WNIH} t_{WNIL}		5		us
$\overline{\text{CTS}}$ low level width	t_{WCTL}		$2T$		ns

Remarks: n represents the number of wait states. n=0 means no wait.

Parameter	Symbol	Test condition	MIN.	MAX.	Unit
INT setup time to CLKOUT ↓	t_{SIRK}		25		ns
CLKOUT ↓ → INTAK ↓ delay time	t_{DKIA}		15	75	ns
INT hold time from INTAK ↓	t_{HIAIQ}		0		ns
INTAK low level width	t_{WIAL}		2T-25		ns
INTAK high level width	t_{WIAH}		T-25		ns
INTAK ↓ → data delay time	t_{DIAD}			2T-100	ns
Data hold time from INTAK ↓	t_{HIAD}		0	0.5T	ns
SCK0 cycle time	t_{CYTK}		1000		ns
SCK0 high, low level width	t_{WSTH} t_{WSTL}		450		ns
SCK0 ↓ → TxD delay time	t_{DTKD}			210	ns
SCK0 ↓ → TxD hold time	t_{HTKD}		20		ns
CTS0 cycle time	t_{CYRK}		1000		ns
CTS0 high, low level width	t_{WSRH} t_{WSRL}		420		ns
RxD setup time to CTS0, hold time from CTS0 ↓	t_{SRDK} t_{HKRD}		80		ns

Comparator characteristics

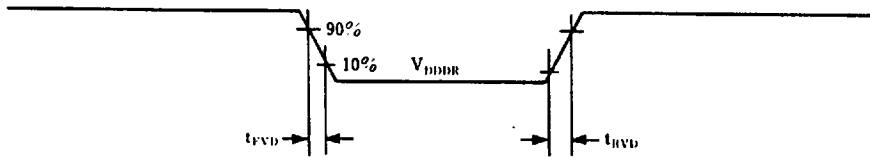
uPD70335(A)-9 ($T_a = -40$ to $+85^{\circ}\text{C}$, $V_{DD} = +5.0\text{V} \pm 5\%$)

Parameter	Symbol	Test condition	MIN.	TYP.	MAX.	Unit
Comparison accuracy	V_{ACOMP}				± 100	mV
Threshold voltage	V_{TH}		0		$V_{DD} + 0.1$	V
Comparison time	t_{COMP}		64		6.5	t_{CYK}
PT input voltage	V_{IPT}		0		V_{DD}	V

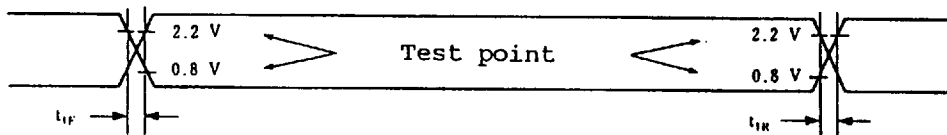
Data memory STOP mode low supply voltage data retention characteristics ($T_a = -40$ to $+85^{\circ}\text{C}$)

Parameter	Symbol	Test condition	MIN.	MAX.	Unit
Data retention supply voltage	V_{DDDR}		2.5	5.5	V
V_{DD} rising, falling time	t_{RVD} , t_{FVD}		200		us

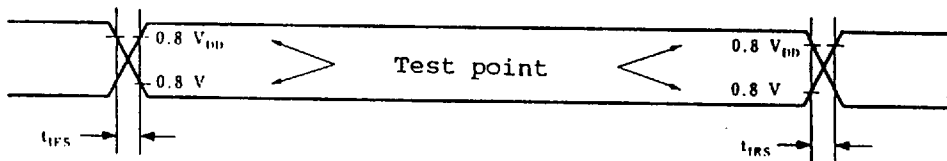
Data retention timing



AC test input waveform (except for RESET, NMI, X1, or X2)

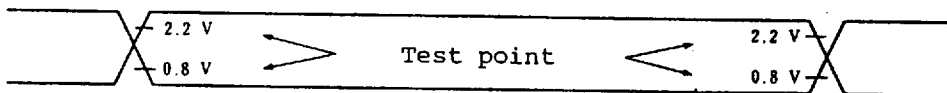


AC test input waveform (RESET, NMI, X1, X2)

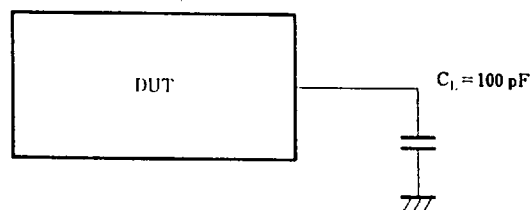


AC test output test points

Output load condition: 100 pF

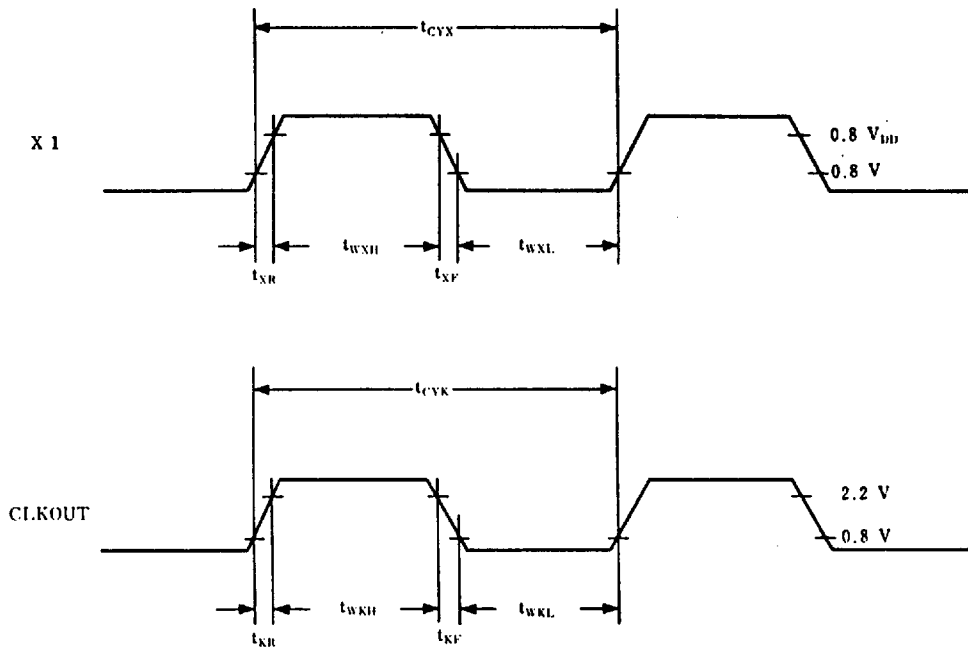


Load condition

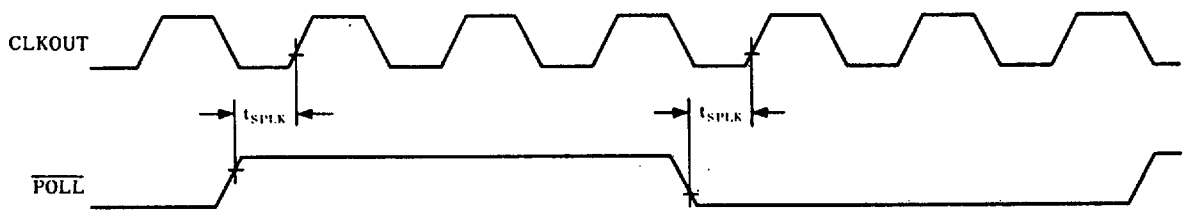


Caution: If the load capacitance exceeds 100 pF because of the circuit configuration, set the load capacitance of the device to 100 pF or less by inserting a buffer, etc.

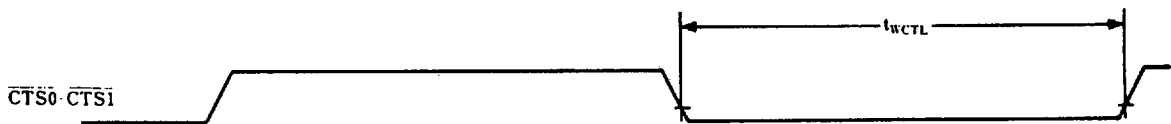
Clock timing



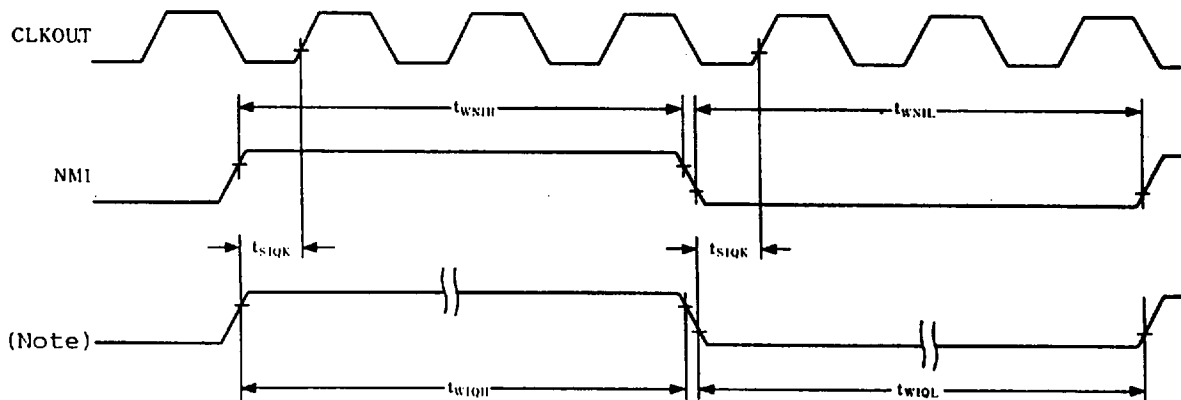
$\overline{POLL}$ input timing



$\overline{CTS0}$ - $\overline{CTS1}$ input timing

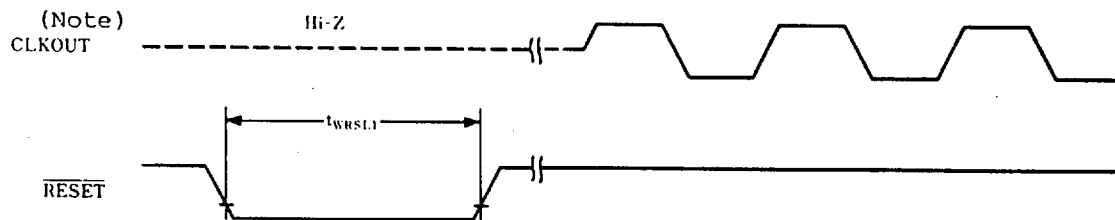


Interrupt input/DMA input timing



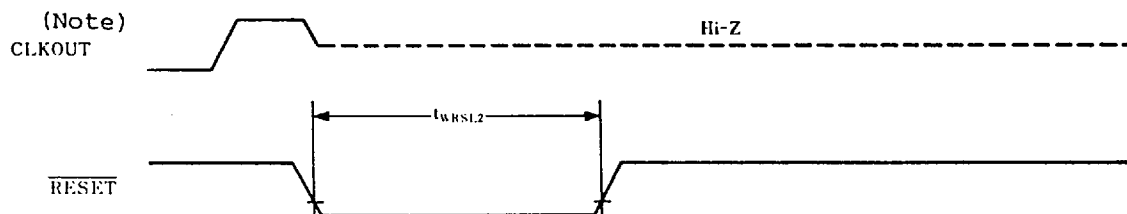
RESET input timing

At STOP mode release or power on reset:



Note: The CLKOUT signal is set in CLKOUT output, then output.

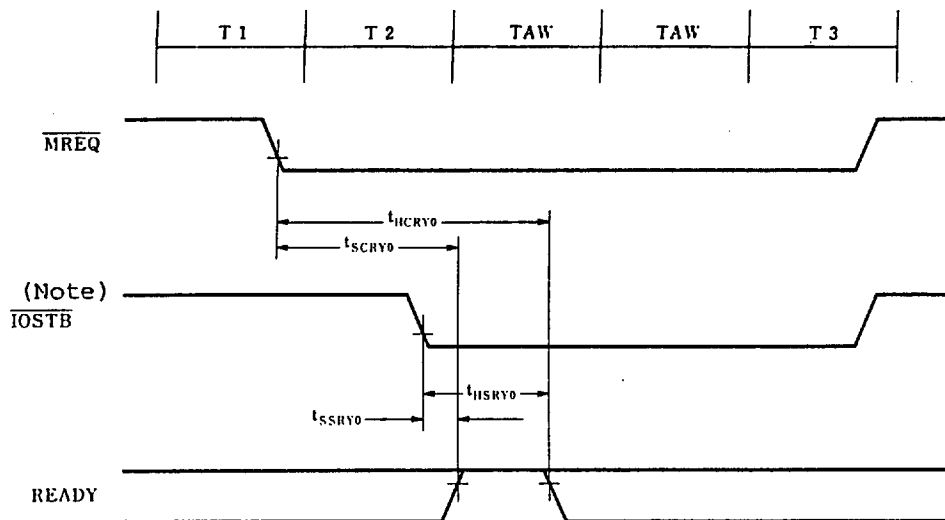
At system reset:



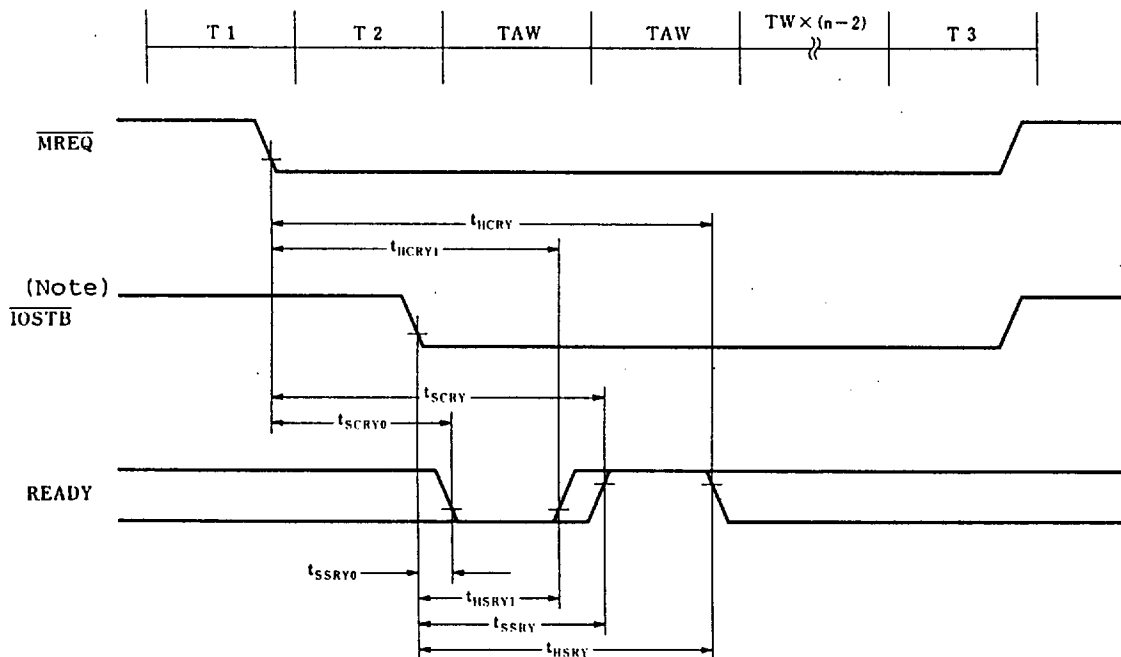
Note: CLKOUT output is set in the input port when RESET is input.

Ready timing

When two wait states are inserted:



When extra (n-2) wait states are inserted:

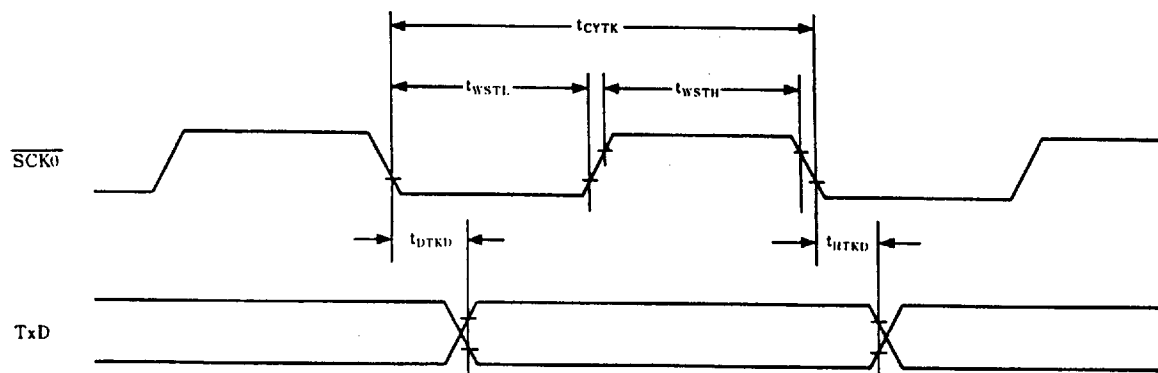


Note: Only I/O cycle

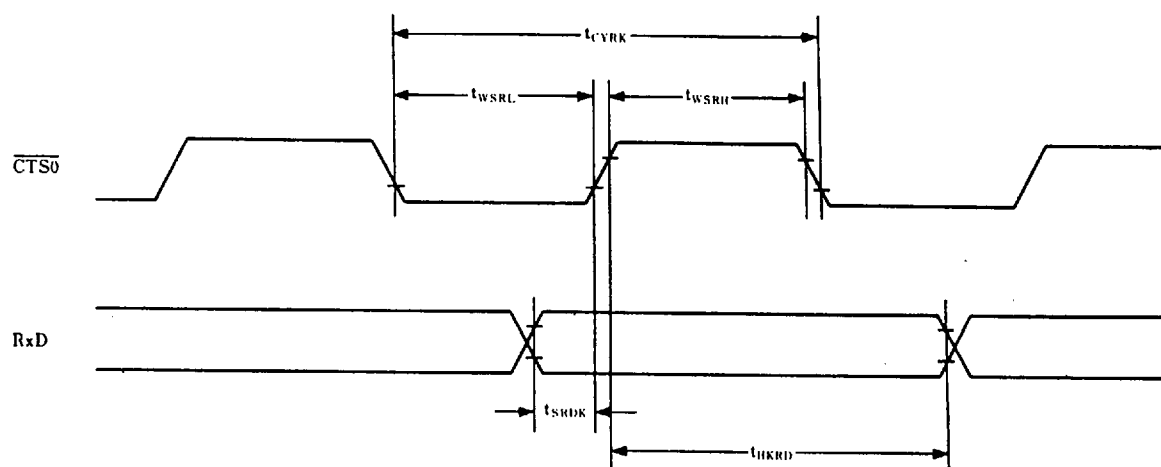
Caution: For wait state insertion by external READY signal, the wait control register (WTC) must be set to 11 (two waits + inserted states by READY pin)

Serial operation

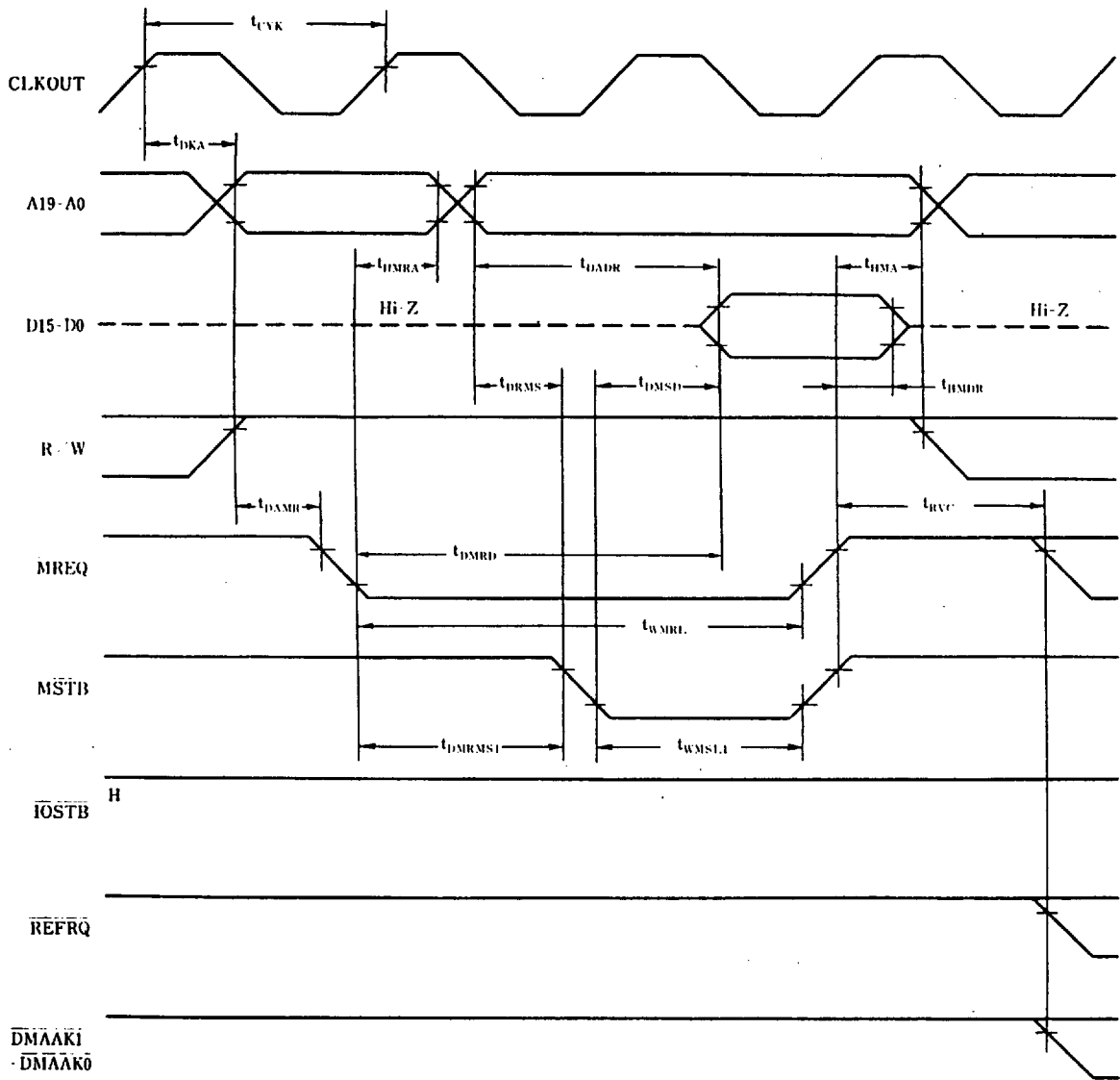
In I/O interface mode transmission



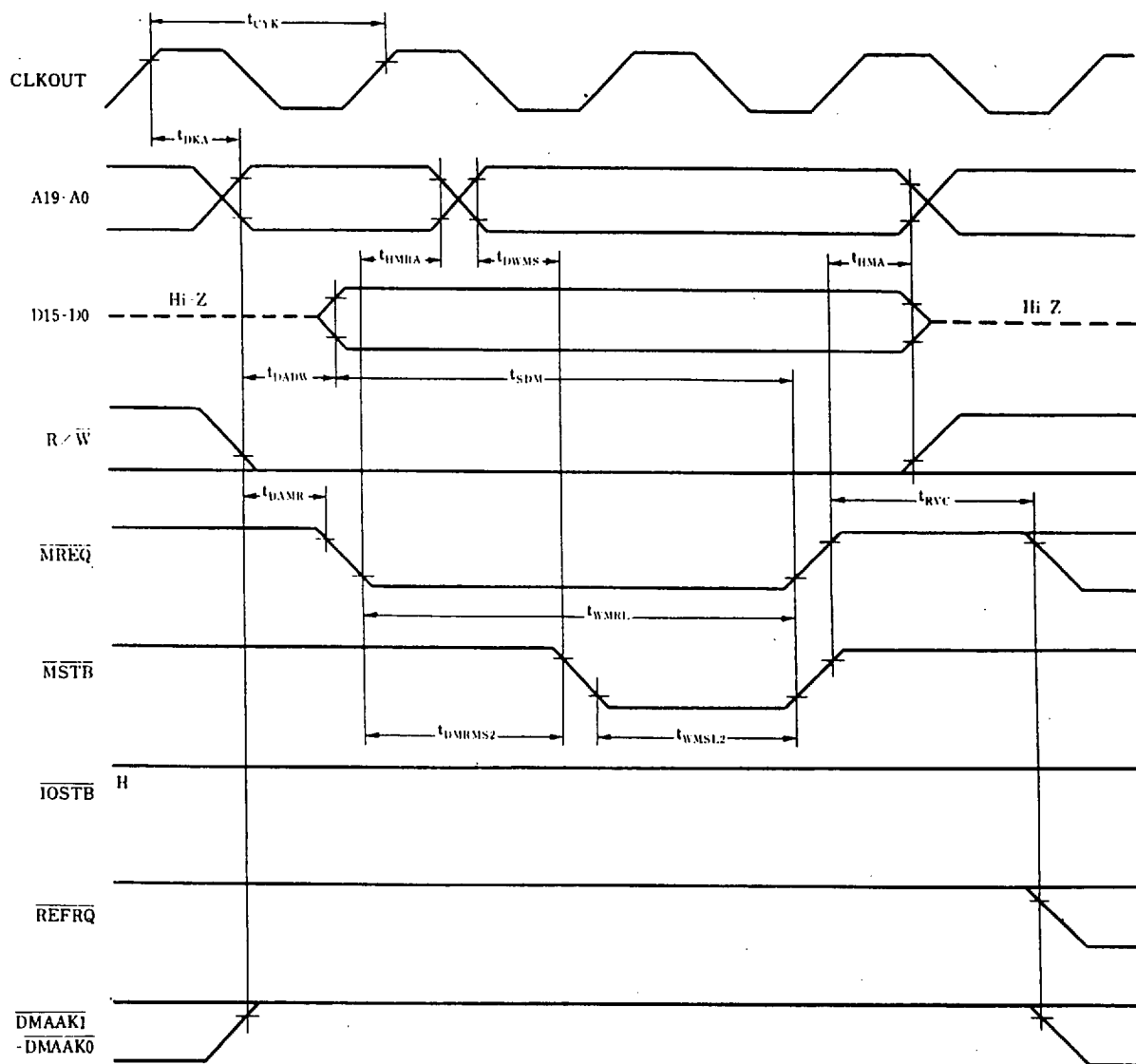
In I/O interface mode reception



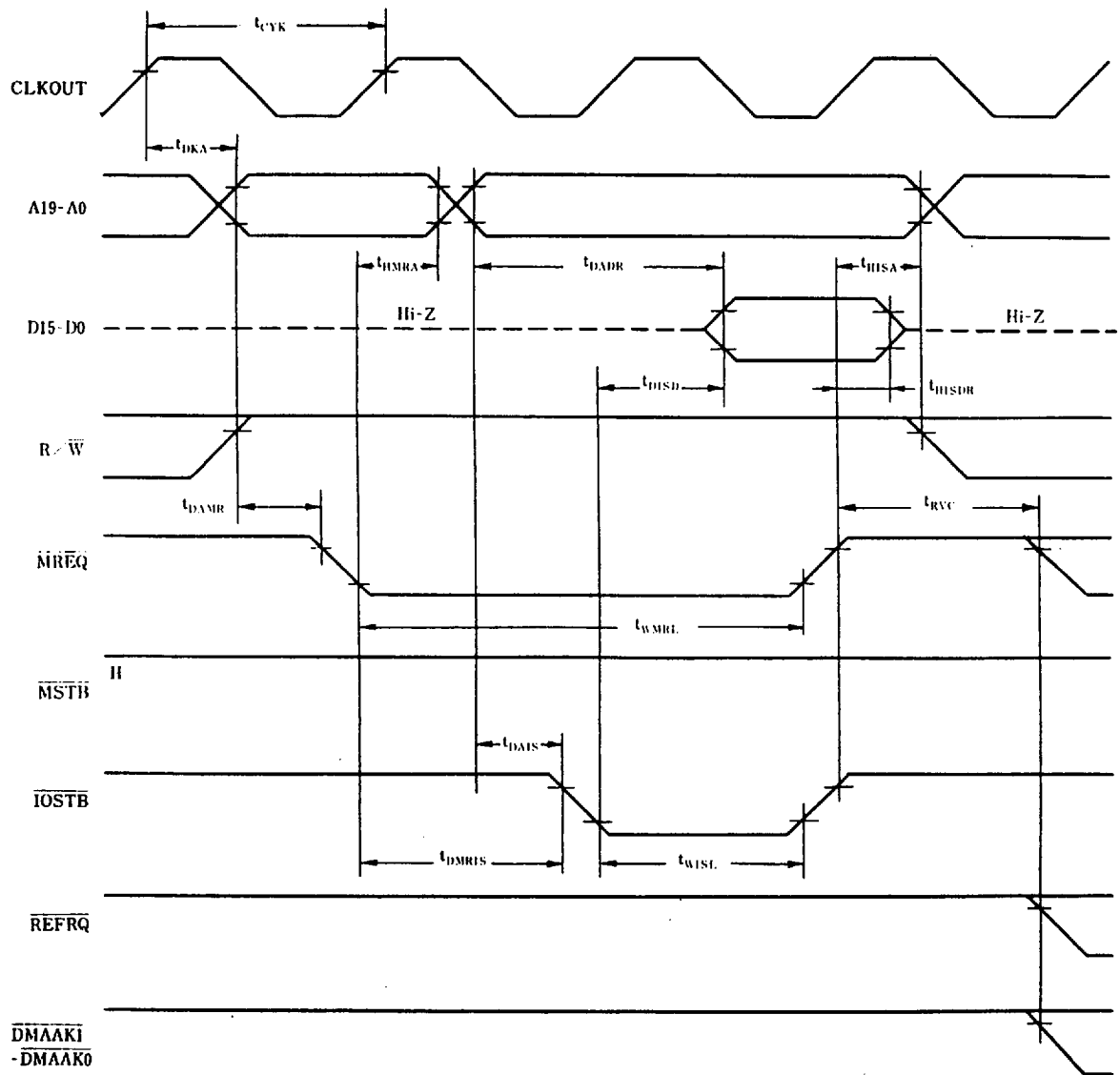
Read operation



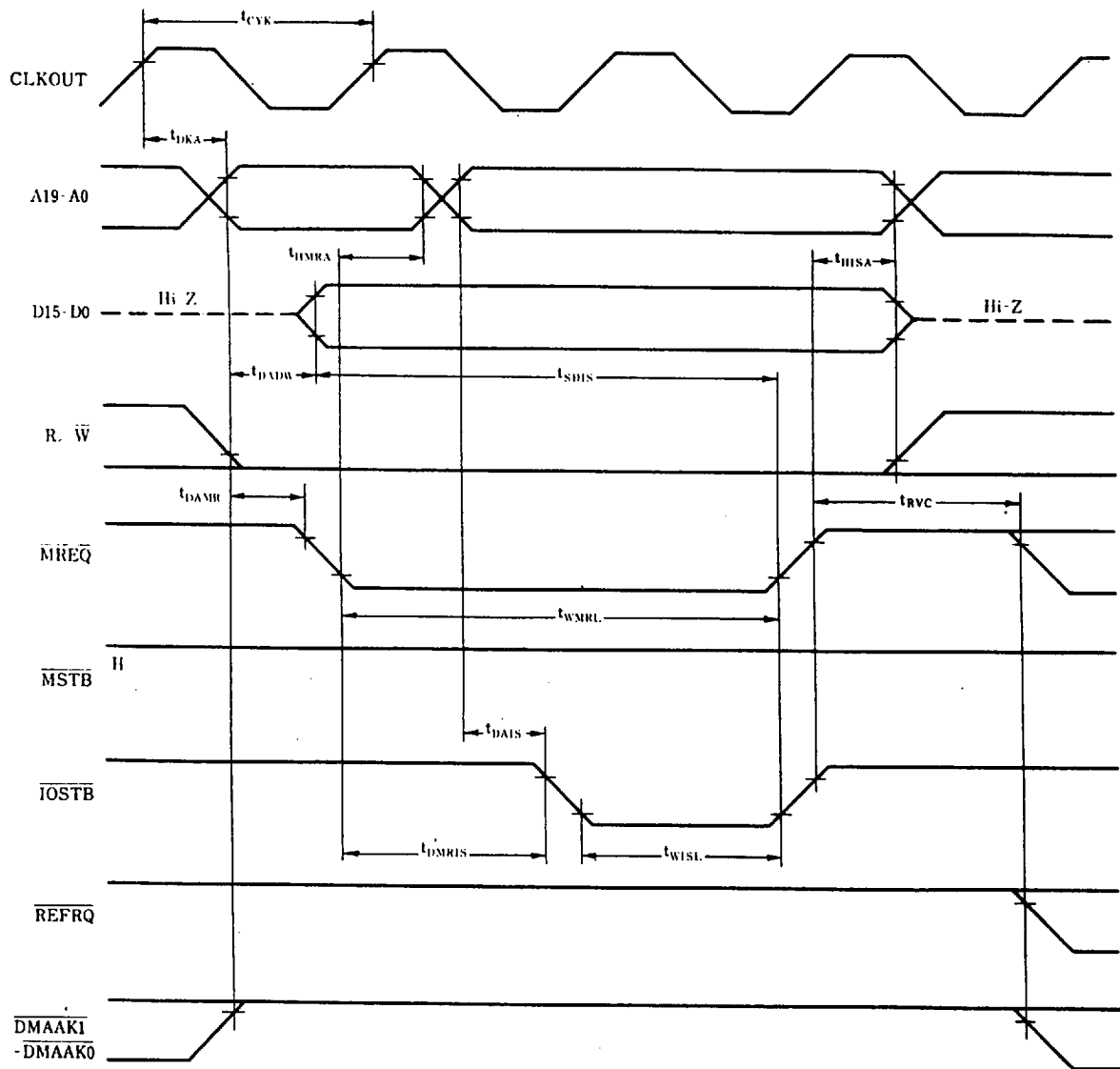
Write operation



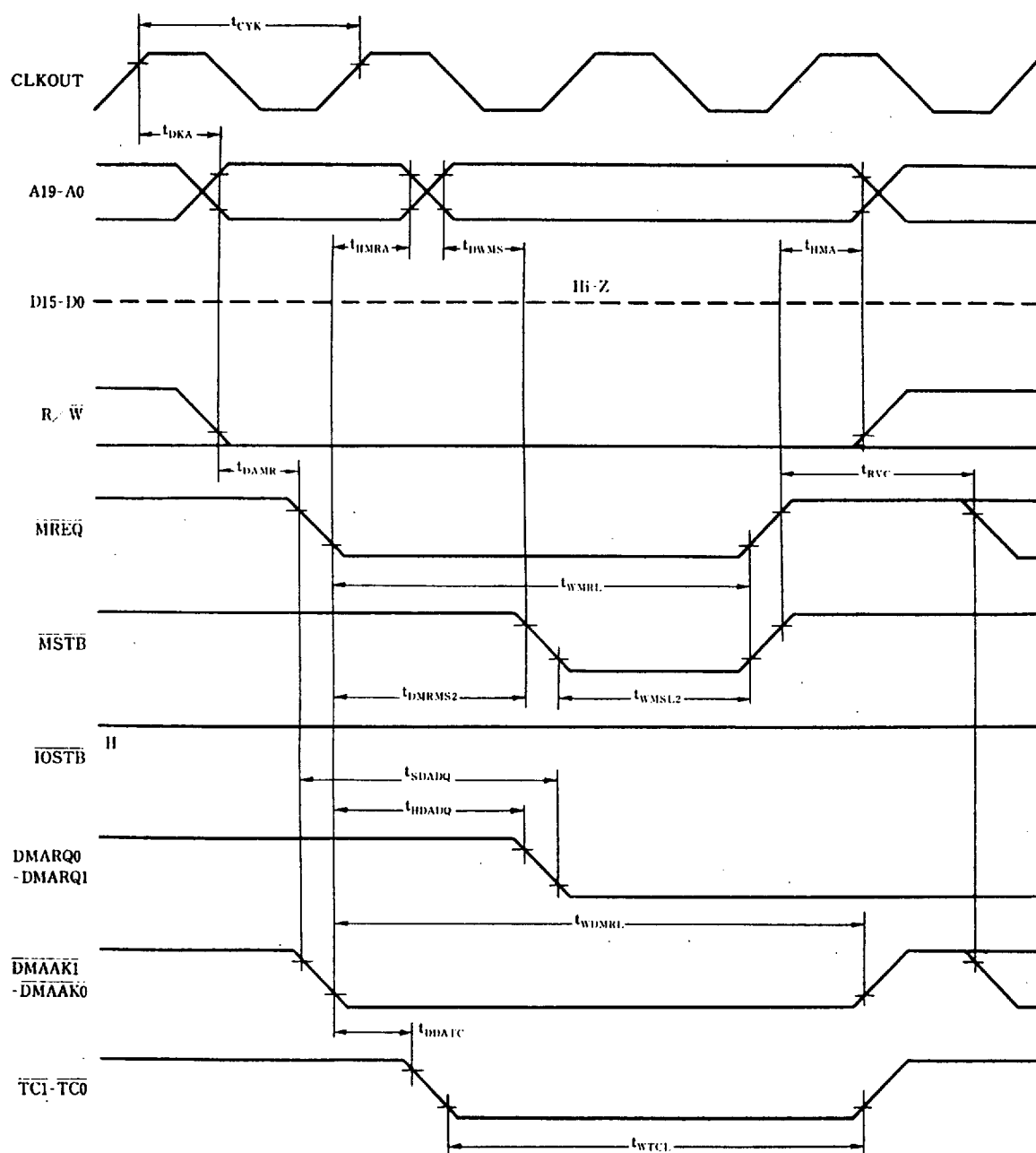
I/O read timing



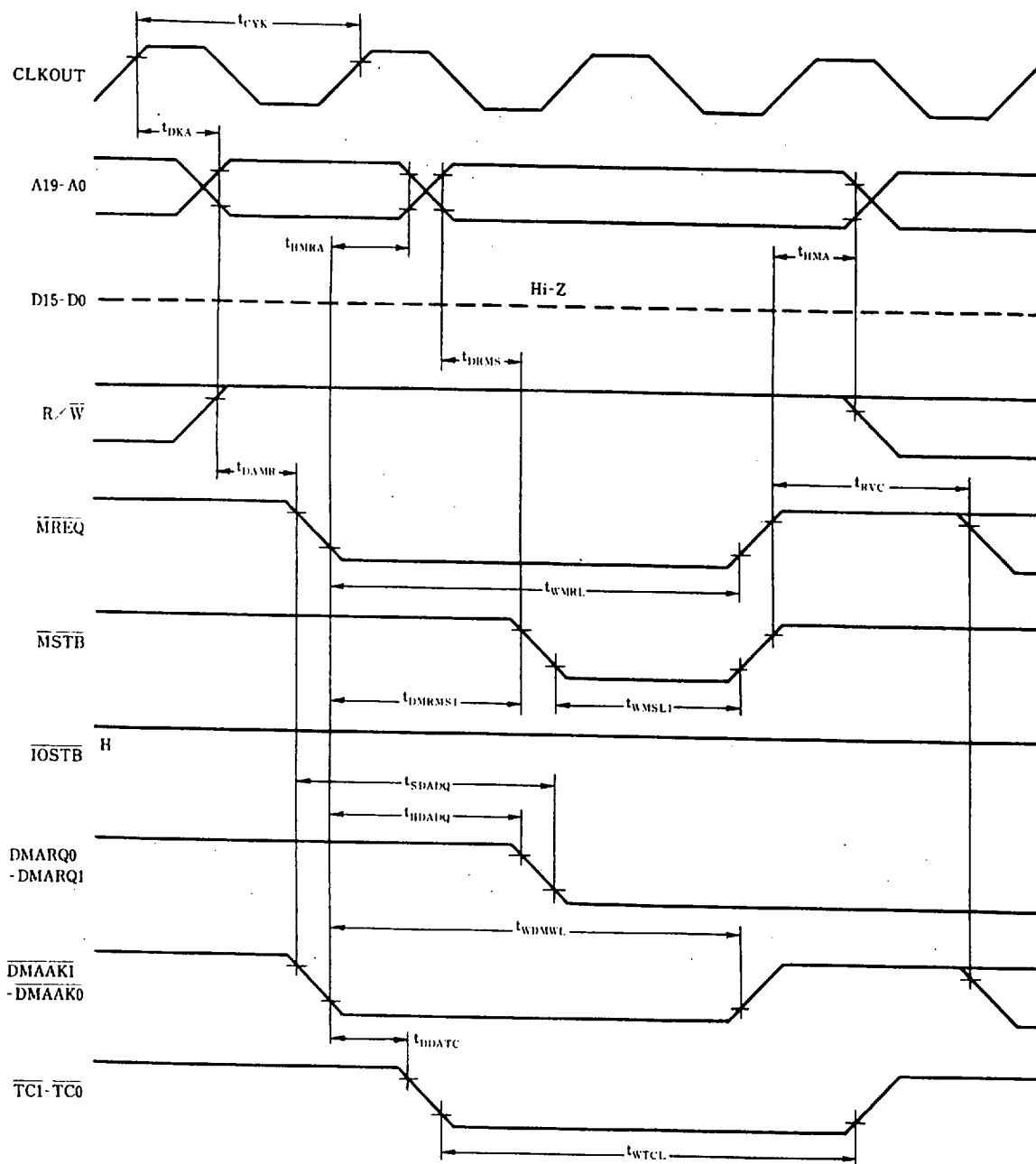
I/O write timing



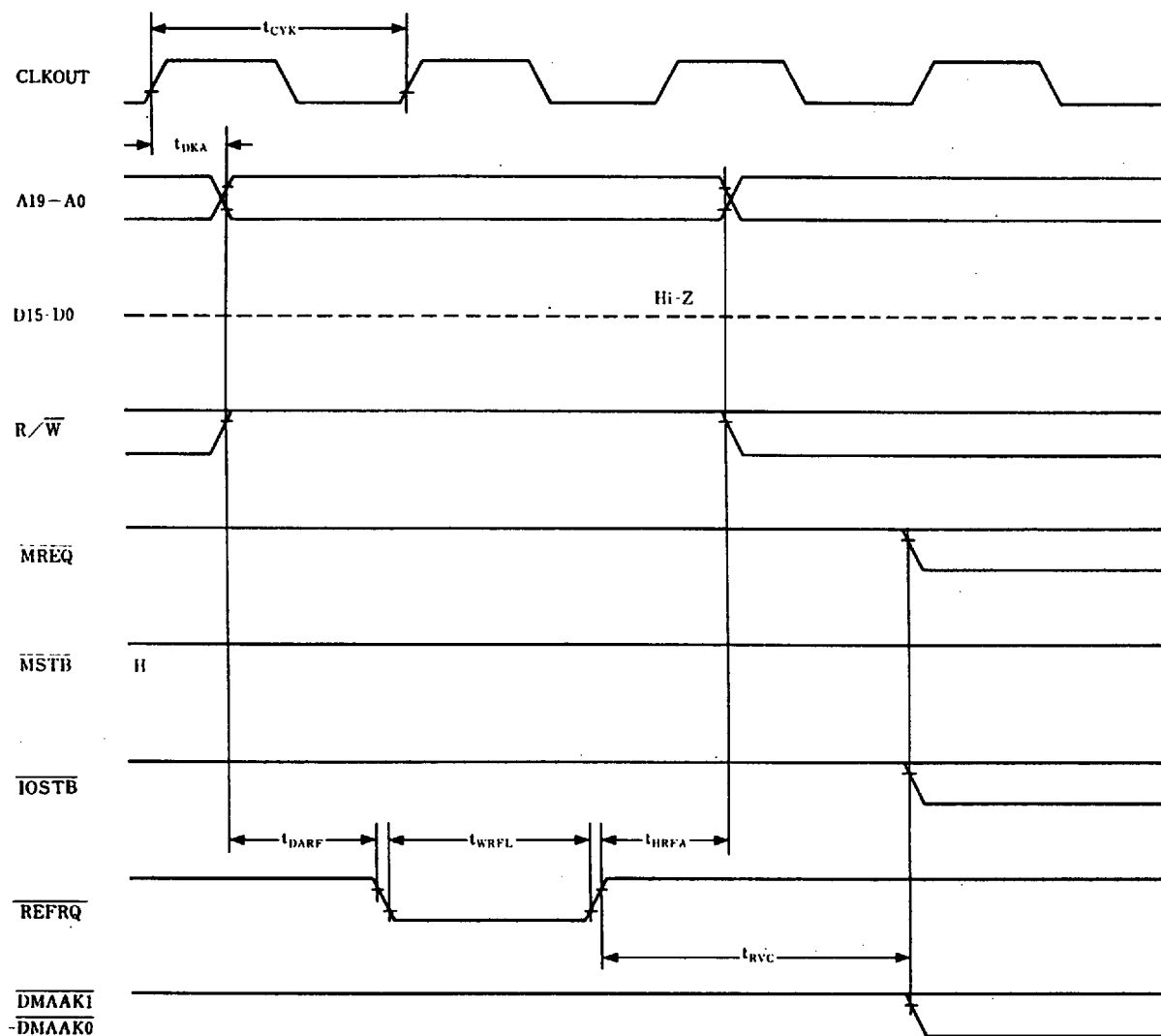
DMA (I/O to memory) timing



DMA (memory to I/O) timing

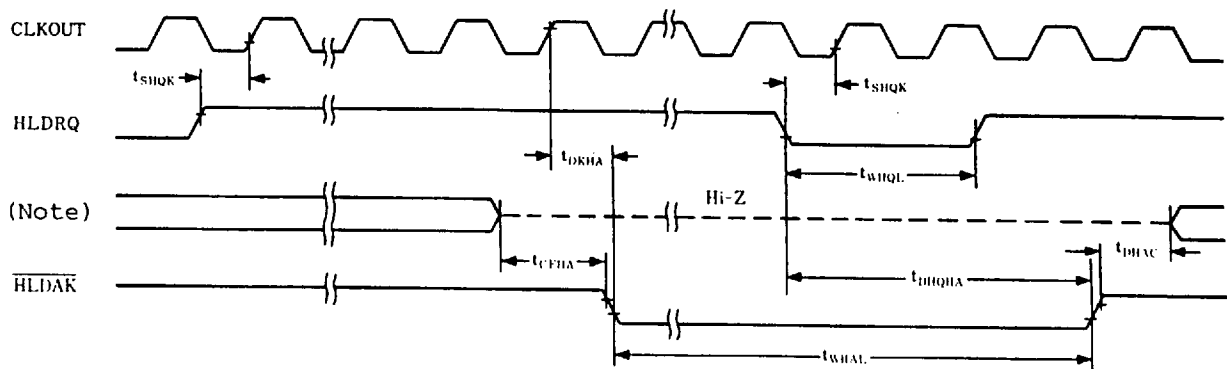


Refresh timing

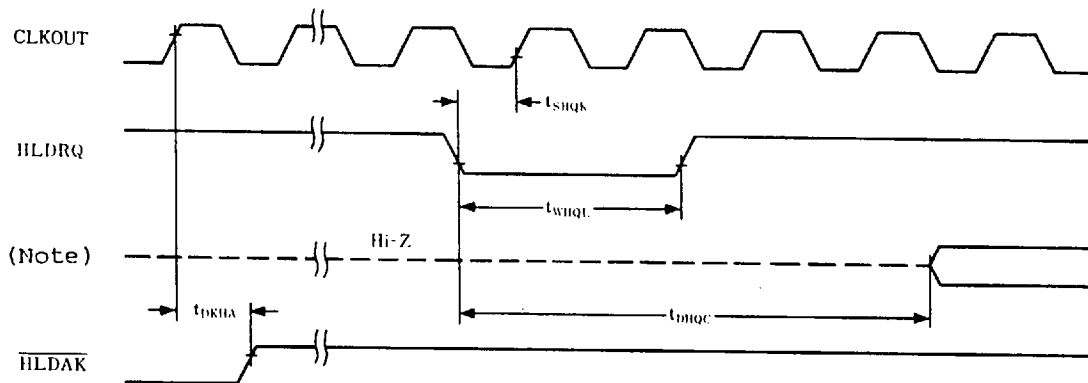


Hold request/acknowledge timing

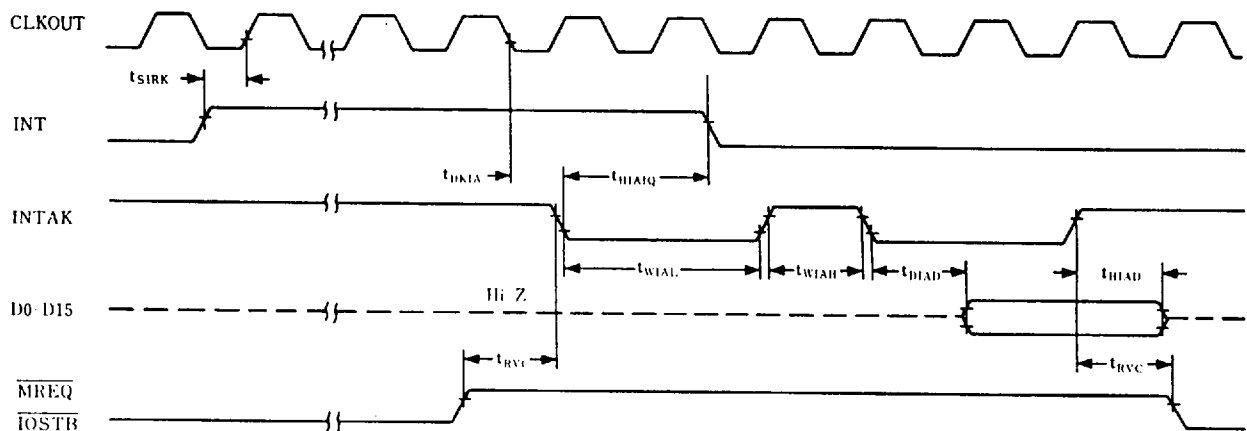
Normal mode



HOLD mode release when memory is refreshed



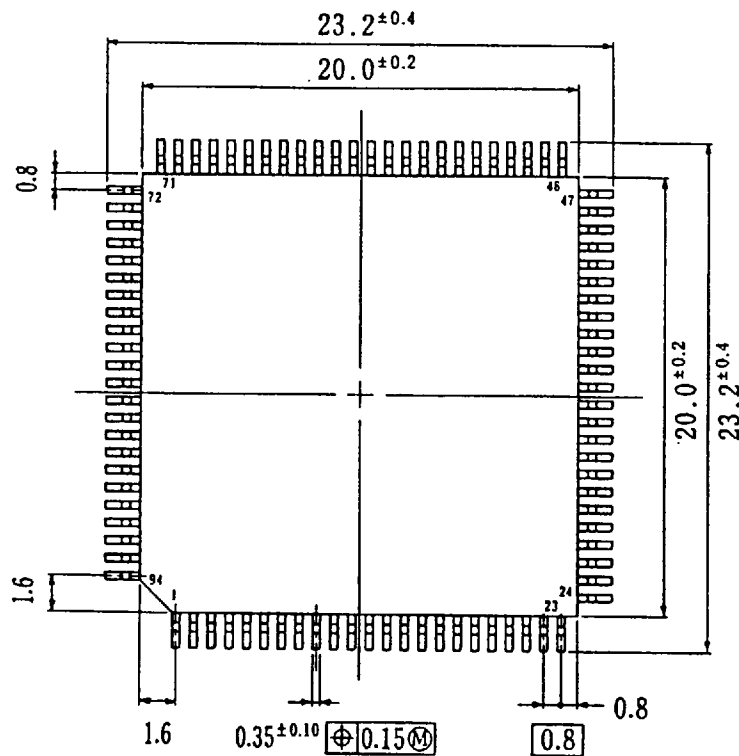
External interrupt request/acknowledge timing



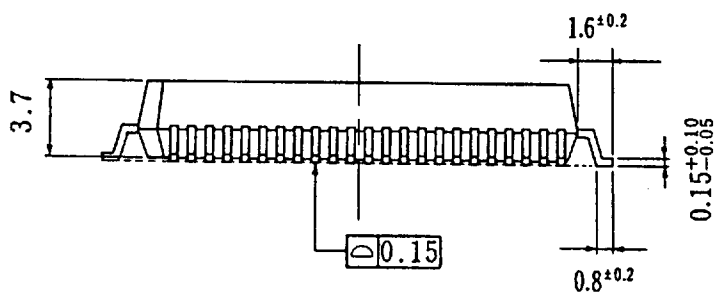
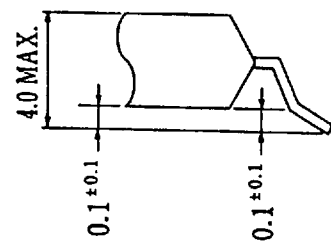
4. PACKAGE INFORMATION

Package Information of 94-pin Plastic QFP (□20)

(Dimension unit: mm)

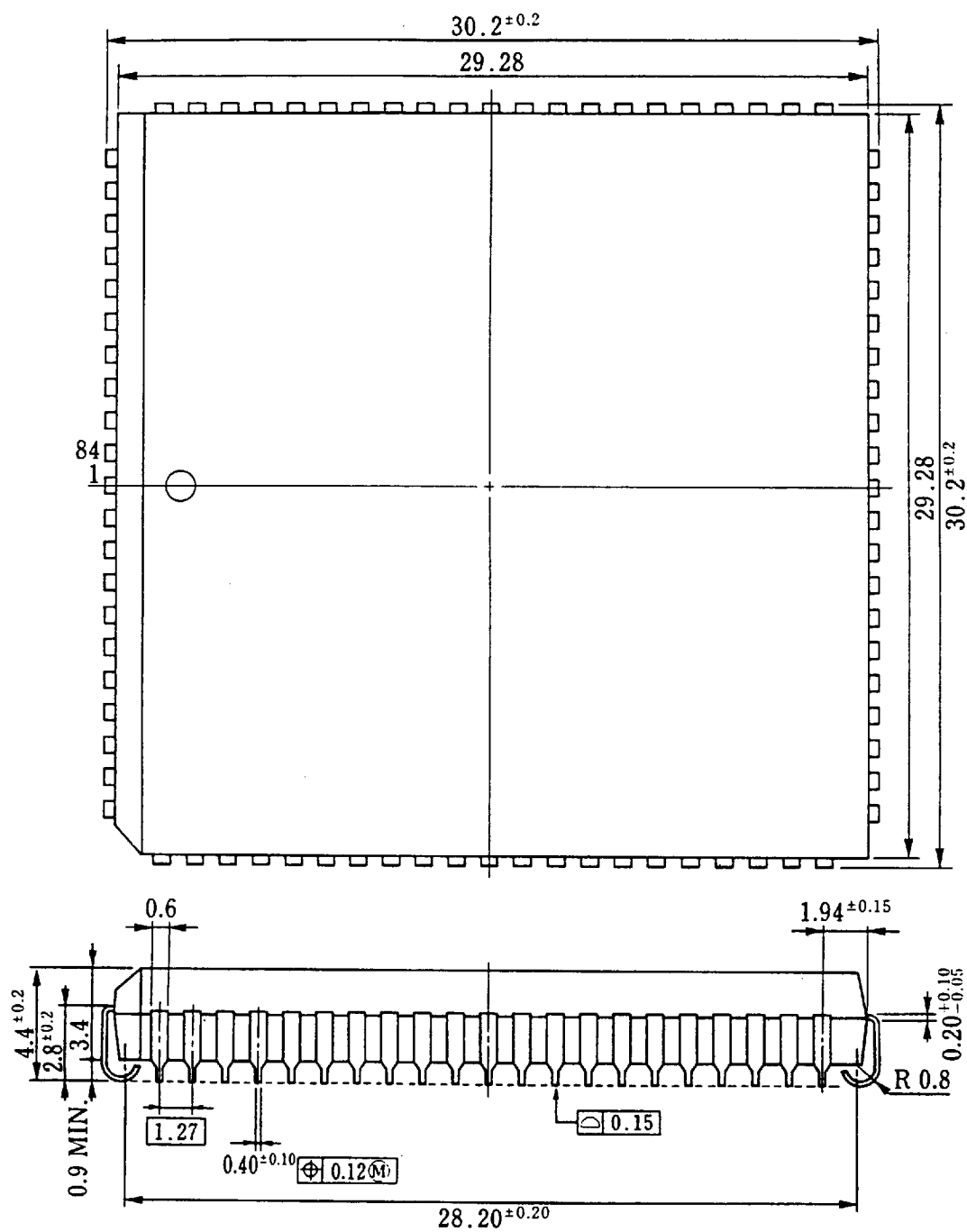


Detailed drawing of
pin tip form



S94GJ-80-5BG-1

84-pin Plastic Leaded Chip Carrier ($\square 1150$) (Dimension unit: mm)



P84L-50A3-1